

D2S6M

Schottky Barrier Diodes
60V, 2A

Feature

- High Recovery Speed
- Low V_F
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): AX078



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : $T_I=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T_{STG}		-40 to 150	$^\circ\text{C}$
Junction temperature	T_J		150	$^\circ\text{C}$
Repetitive peak reverse voltage	V_{RRM}		60	V
Repetitive peak surge reverse voltage	V_{RRSM}	Pulse width 0.5ms, duty=1/40	65	V
Average forward current	$I_F(AV)$	50Hz sine wave, Resistance load, With heatsink, $,T_I=119^\circ\text{C}$	2	A
Average forward current	$I_F(AV)$	50Hz sine wave, Resistance load, With heatsink, $T_a=25^\circ\text{C}$	1.2	A
Surge forward current	I_{FSM}	50Hz sine wave, Non-repetitive, 1cycle, Peak value, $T_J=25^\circ\text{C}$	60	A
Repetitive peak surge reverse power	P_{RRSM}	Pulse width 10 μs , $T_J=25^\circ\text{C}$	330	W

* : See the original Specifications

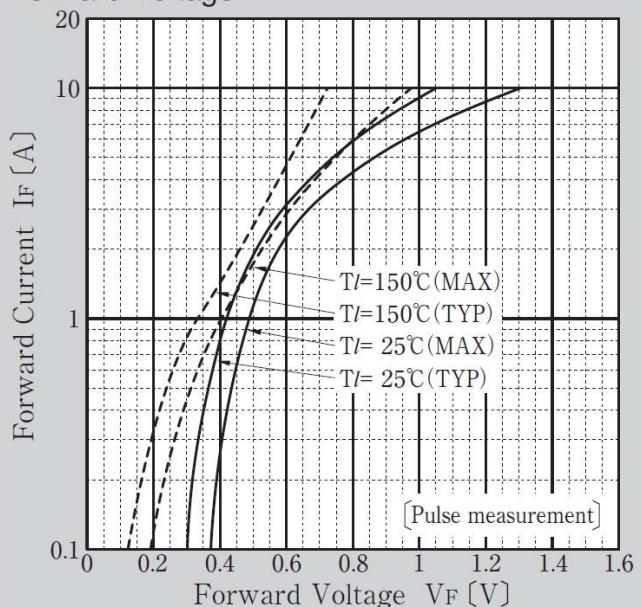
Electrical Characteristics (unless otherwise specified : T_I=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Forward voltage	V _F	IF=2A, Pulse measurement			0.58	V
Reverse current	I _R	VR=60V, Pulse measurement			2	mA
Total capacitance	C _t	f=1MHz, VR=10V		90		pF
Thermal resistance	R _{th(j-l)}	Junction to lead			17	°C/W
Thermal resistance	R _{th(j-a)}	Junction to ambient			105	°C/W

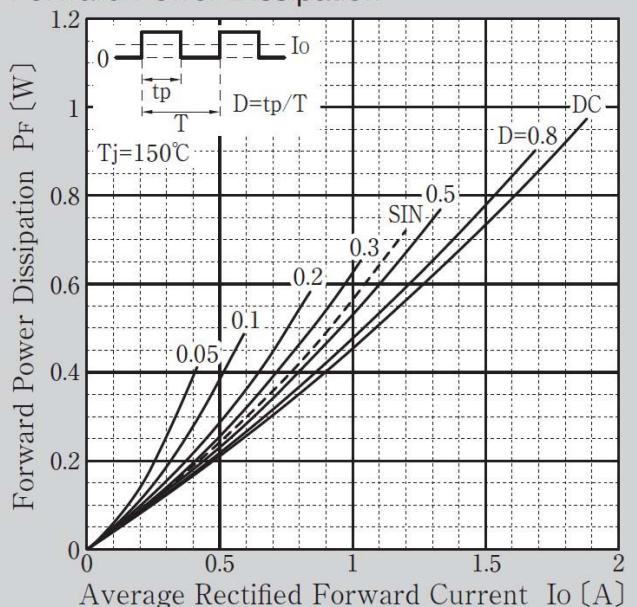
* : See the original Specifications

CHARACTERISTIC DIAGRAMS

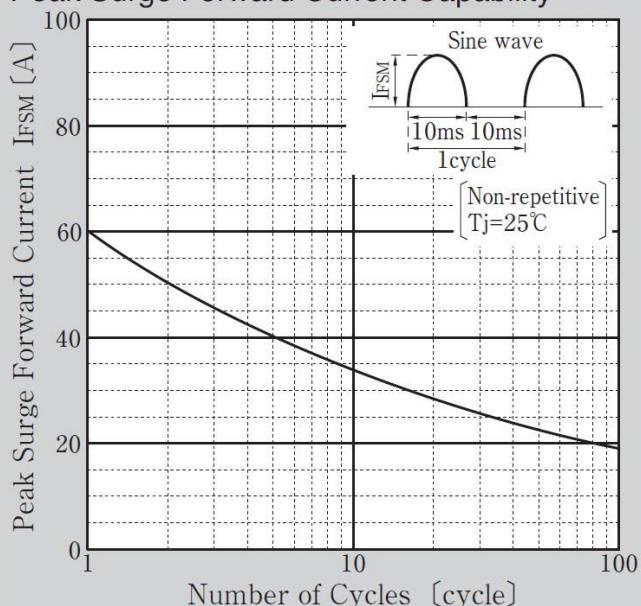
Forward Voltage



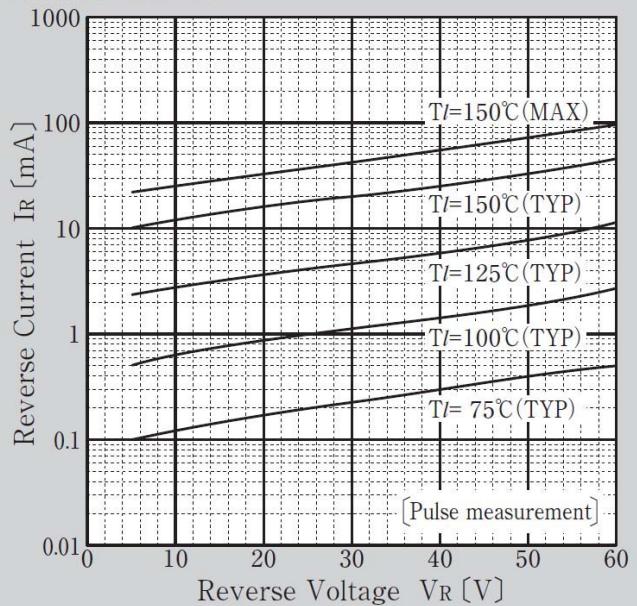
Forward Power Dissipation

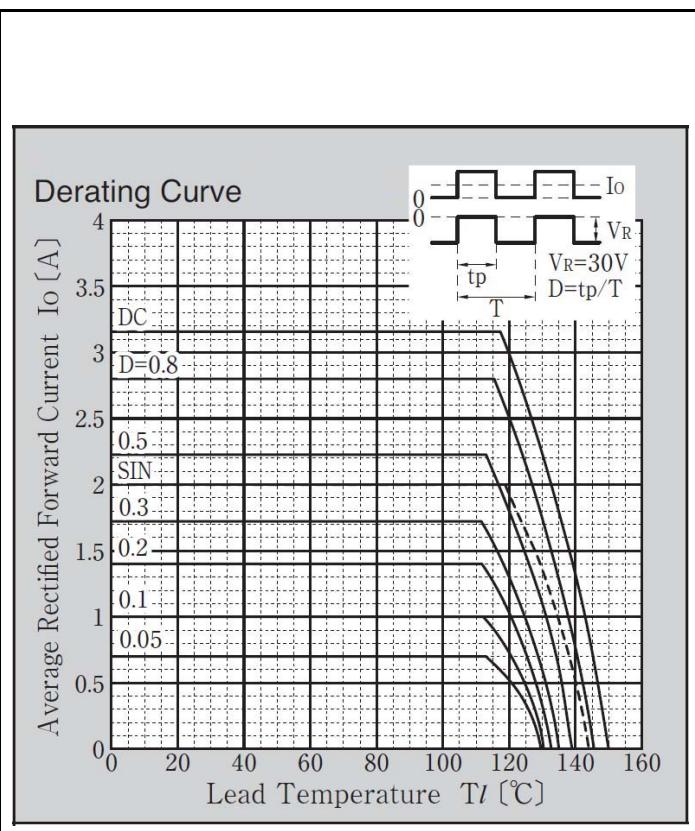
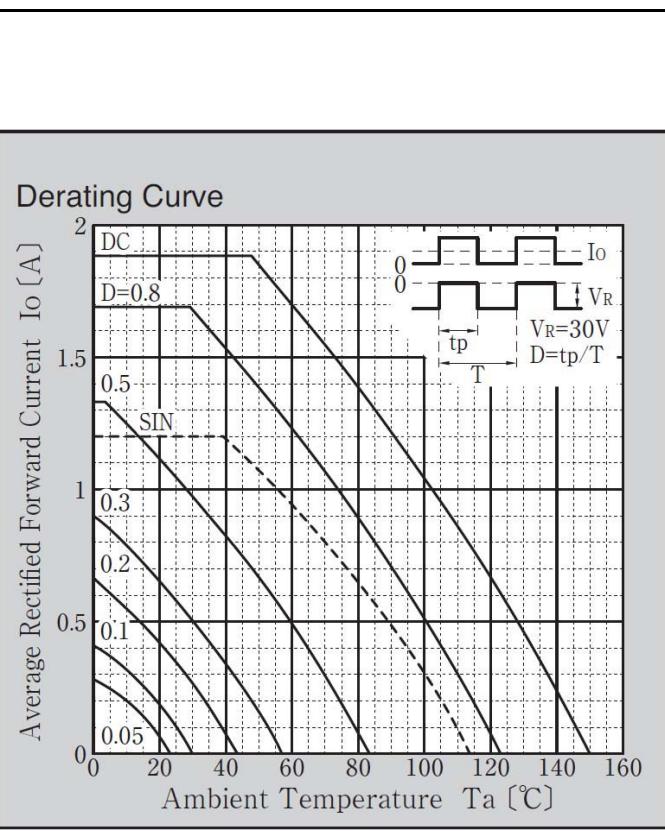
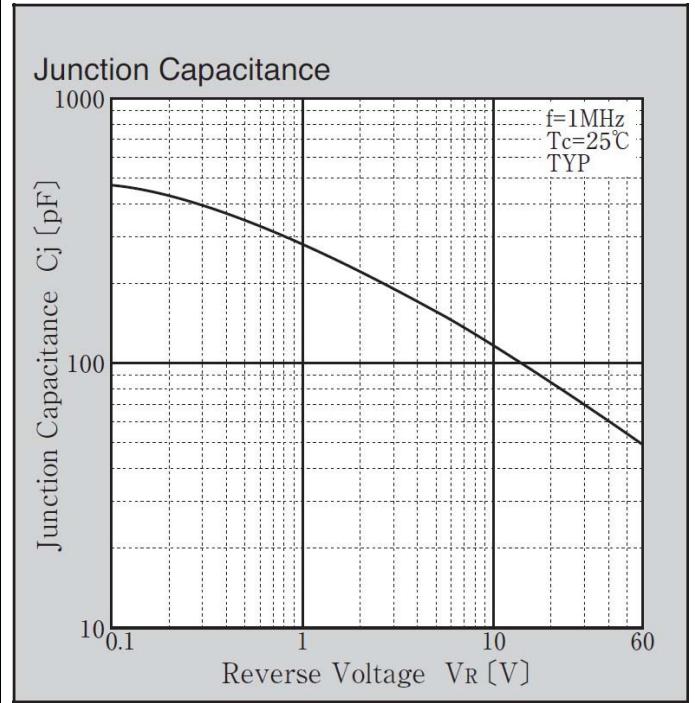
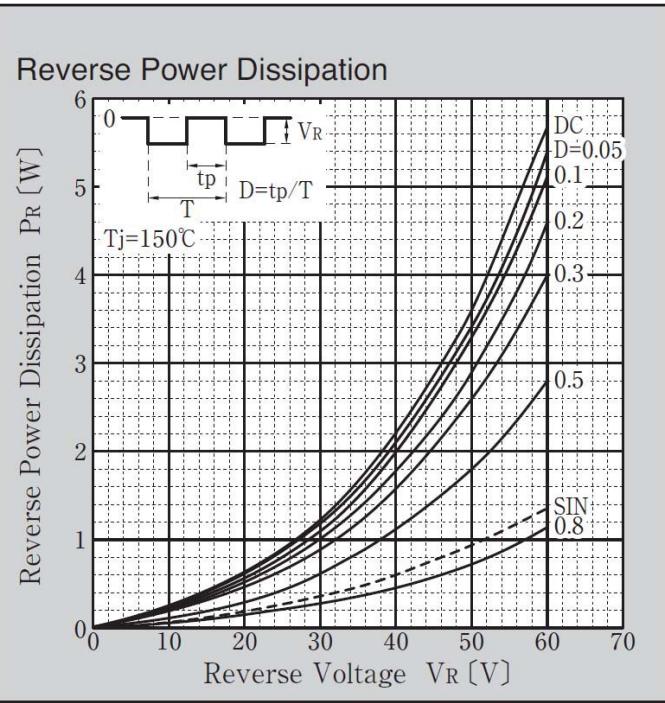


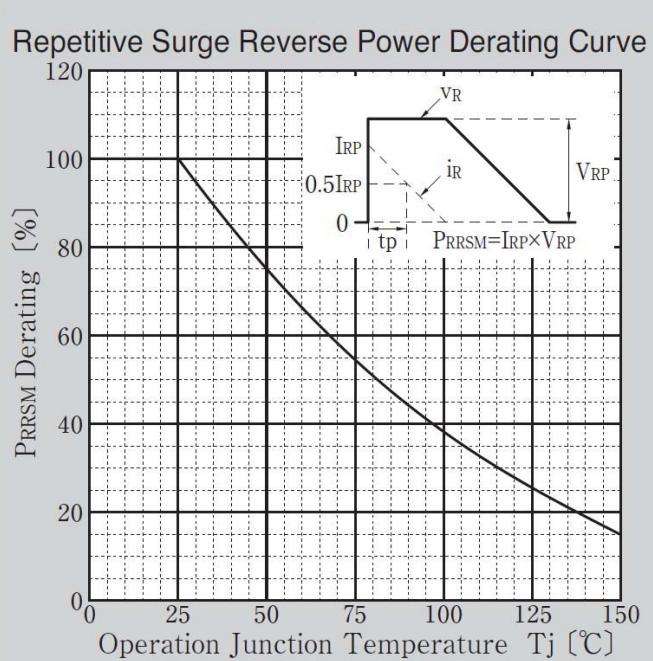
Peak Surge Forward Current Capability



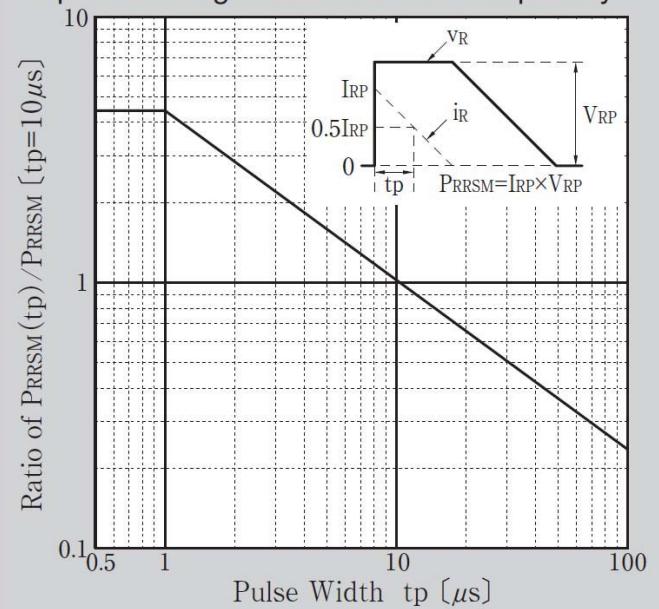
Reverse Current







Repetitive Surge Reverse Power Capability



Outline Dimensions

unit:mm

scale: 2/1

A4

JEDEC Code	—
JEITA Code	—
House Name	AX078

